



UTG28N65LND2

Insulated Gate Bipolar Transistor

650V TRENCH GATE FIELD-STOP IGBT

■ DESCRIPTION

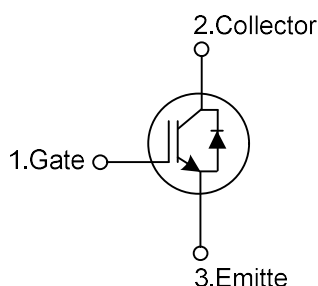
The UTC **UTG28N65LND2** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

The UTC **UTG28N65LND2** is suitable for the resonant or soft switching applications.

■ FEATURES

- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: $V_{CE(SAT).Typ.}=1.7V$ @ $I_C=28A$, $V_{GE}=15V$ ($T_C=25^{\circ}C$)

■ SYMBOL

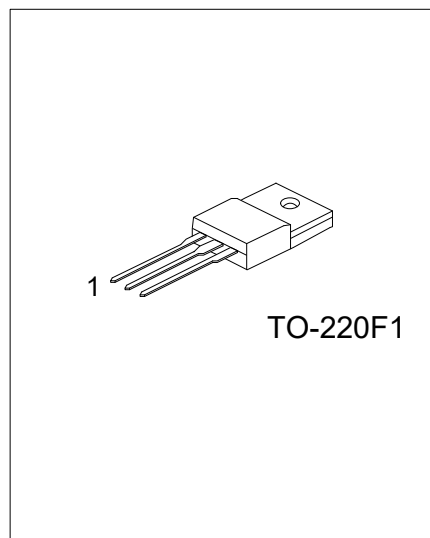


■ ORDERING INFORMATION

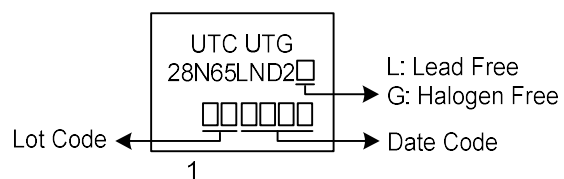
Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UTG28N65LND2L-TF1-T	UTG28N65LND2G-TF1-T	TO-220F1	G	C	E	Tube

Note: Pin Assignment: G: Gate C: Collector E: Emitter

UTG28N65LND2G-TF1-T	(1)Packing Type	(1) T: Tube
	(2)Package Type	(2) TF1: TO-220F1
	(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free



■ MARKING



■ ABSOLUTE MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$, unless otherwise noted)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage	V_{CES}	650	V
Gate-Emitter Voltage	V_{GES}	± 20	V
Transient Gate-emitter voltage ($t_p < 5\text{ ms}$)		± 25	V
Continuous Collector Current	I_C	$T_C=25^{\circ}\text{C}$	A
		$T_C=100^{\circ}\text{C}$	A
Collector Current Pulsed (Note 1)	I_{CM}	112	A
Diode Forward Current	I_F	$T_C=25^{\circ}\text{C}$	A
		$T_C=100^{\circ}\text{C}$	A
Short Circuit Withstand Time $V_{GE} = 15\text{V}$, $V_{CC} \leq 200\text{V}$ Allowed number of short circuits < 1000 Time between short circuits: $\geq 1.0\text{s}$ $T_{VJ} = 25^{\circ}\text{C}$	t_{SC}	8	μs
Power Dissipation ($T_C=25^{\circ}\text{C}$)	P_D	35	W
Operating Junction Temperature	T_J	$-40 \sim +150$	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	$-55 \sim +150$	$^{\circ}\text{C}$

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

Absolute maximum ratings are those values beyond which the device could be permanently damaged.

2. Pulse width limited by maximum junction temperature.

■ THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	θ_{JC}	3.57	$^{\circ}\text{C/W}$

■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Off Characteristics						
Collector-Emitter Breakdown Voltage	BV _{CES}		650			V
Collector Cut-Off Current	I _{CES}	V _{CE} =650V, V _{GE} =0V			5	μA
G-E Leakage Current	I _{GES}	V _{CE} =0V, V _{GE} =±20V			±400	nA
On Characteristics						
Gate to Emitter Threshold Voltage	V _{GE(TH)}	I _C =250μA, V _{CE} =V _{GE}	4.5		7.5	V
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =28A, V _{GE} =15V	T _C =25°C	1.5	2.0	V
			T _C =125°C	1.8		V
Dynamic Characteristics						
Input Capacitance	C _{IES}	V _{CE} =25V, V _{GE} =0V, f=1MHz		1.45		nF
Output Capacitance	C _{OES}			151		pF
Reverse Transfer Capacitance	C _{RES}			33		pF
Switching Characteristics						
Total Gate Charge	Q _G	V _{CE} =520V, I _C =28A, V _{GE} =15V		72		nC
Gate-Emitter Charge	Q _{GE}			23		nC
Gate-Collector Charge	Q _{GC}			31		nC
Turn-On Delay Time	t _{DON}	V _{CC} =400V, I _C =28A, R _G =5Ω, V _{GE} =0~15V, L=500μH		11		ns
Rise Time	t _R			26		ns
Turn-Off Delay Time	t _{DOFF}			59		ns
Fall Time	t _F			118		ns
Turn-On Switching Loss	E _{ON}			1.0		mJ
Turn-Off Switching Loss	E _{OFF}			0.7		mJ
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Forward Voltage Drop	V _F	I _F =28A			2.0	V
Reverse Recovery Time	t _{rr}	I _F =28A, dI/dt=100A/μS,		70		ns
Reverse Recovery Charge	Q _{rr}	V _{CC} =400V		819		μC

■ TEST CIRCUIT AND WAVEFORMS

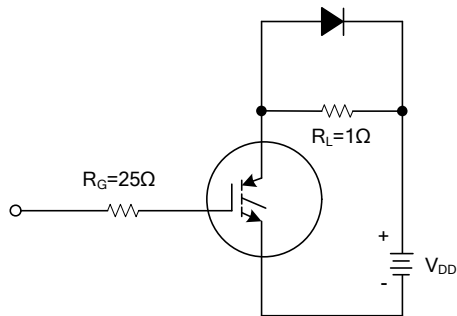


Fig 1. INDUCTIVE SWITCHING TEST CIRCUIT

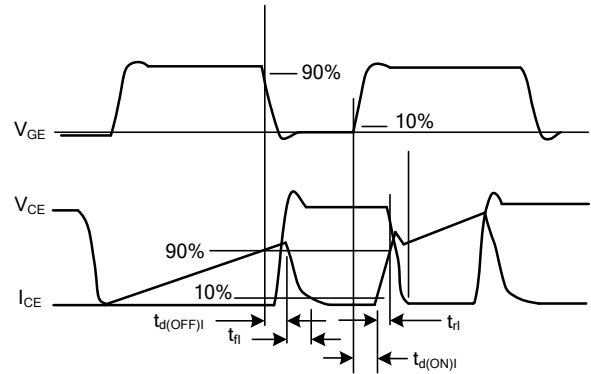
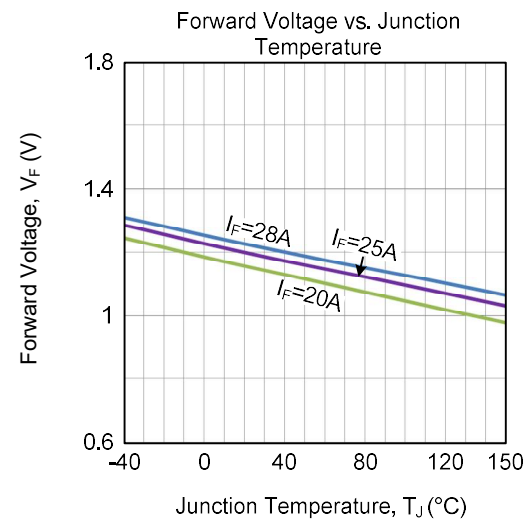
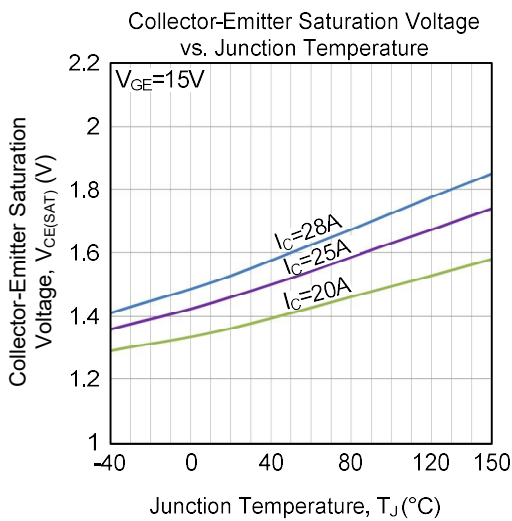
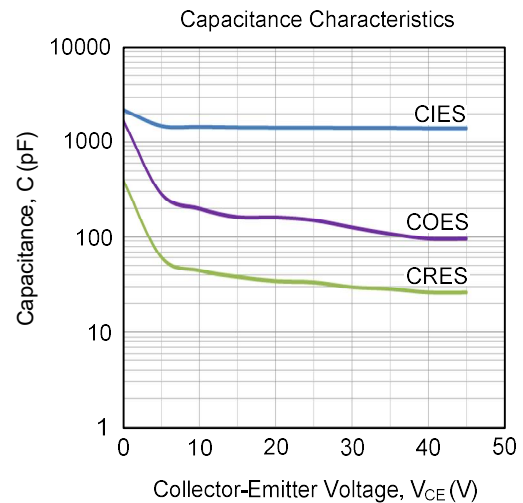
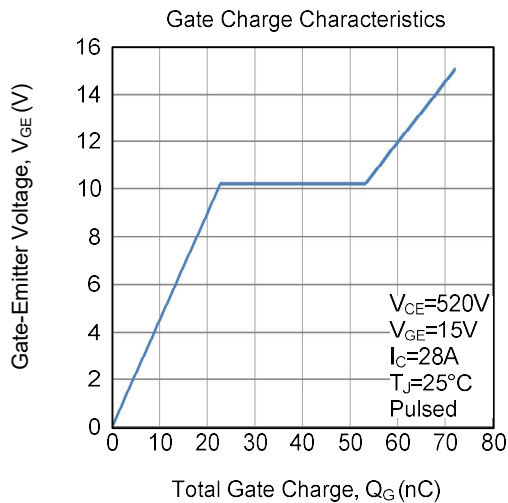
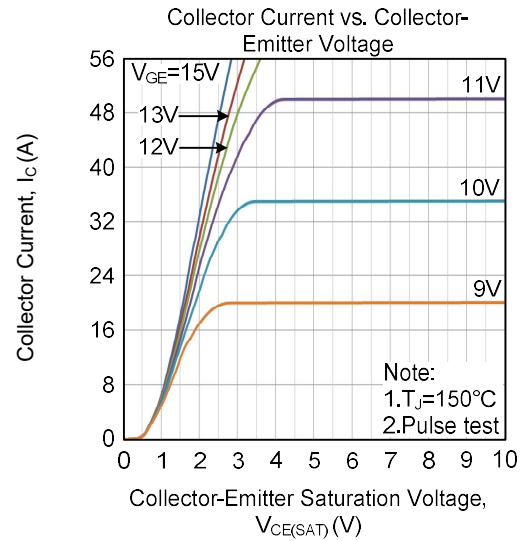
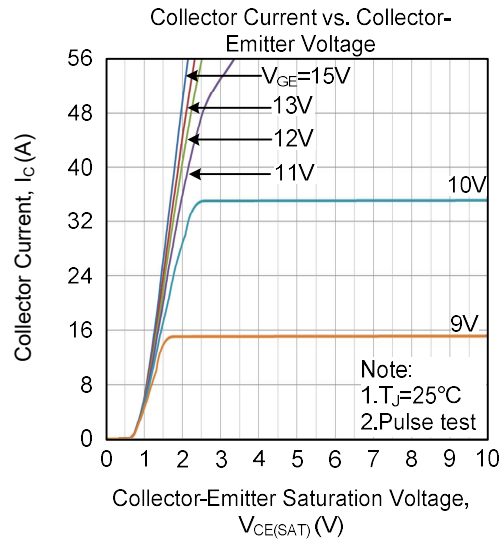
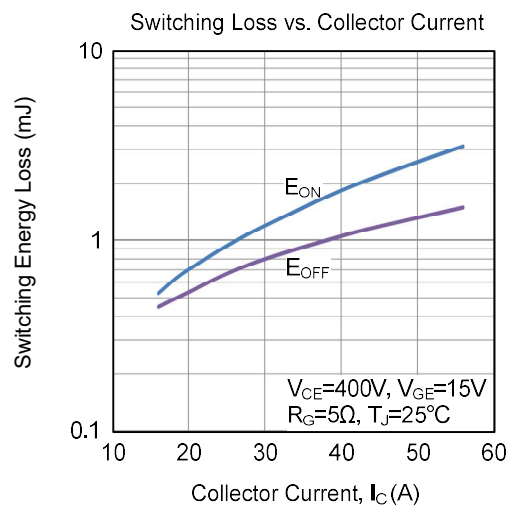
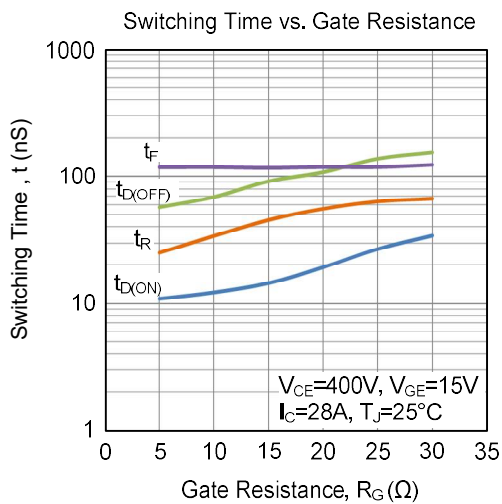
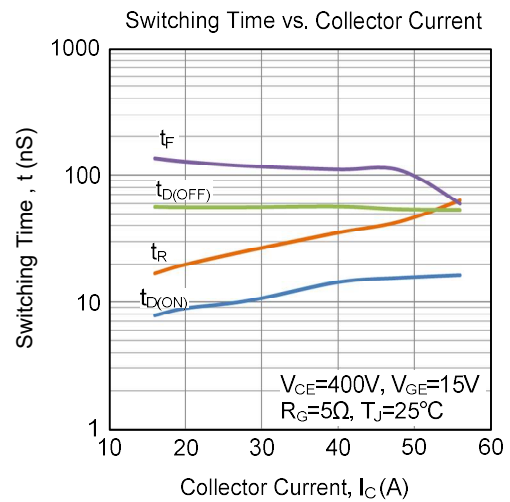
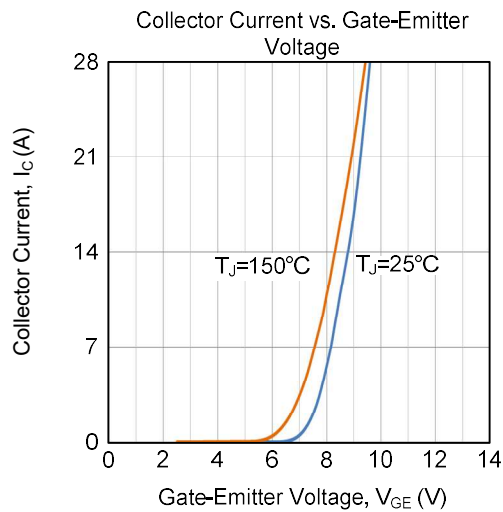
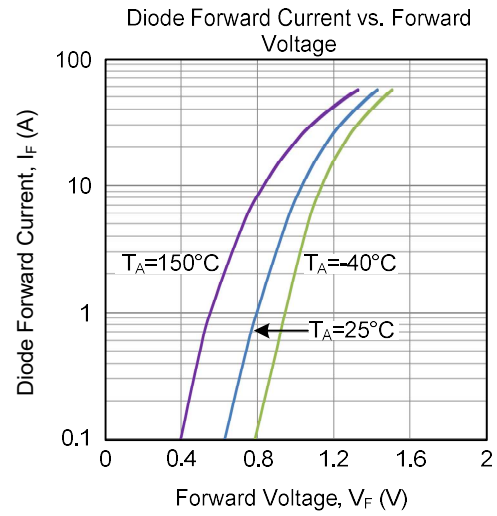
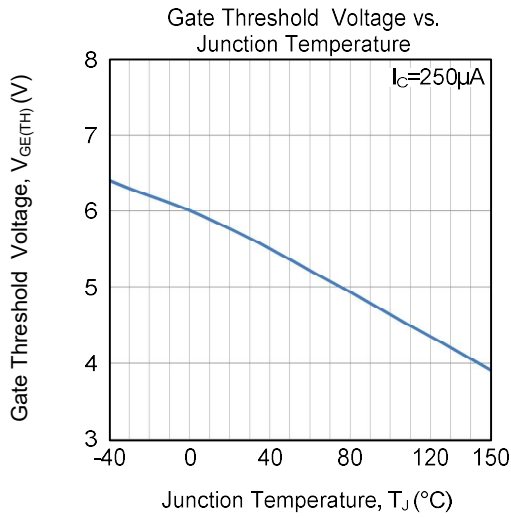


Fig 2. SWITCHING TEST WAVEFORMS

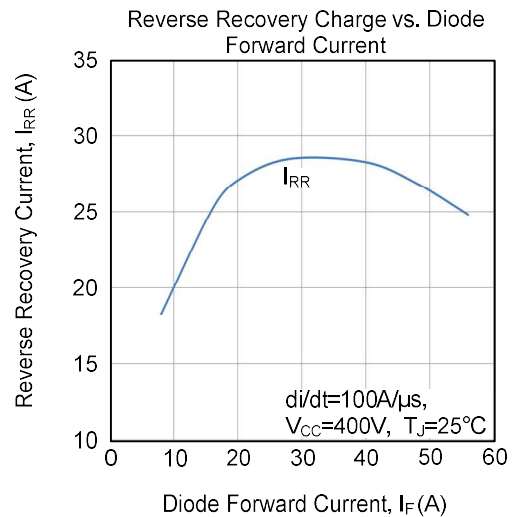
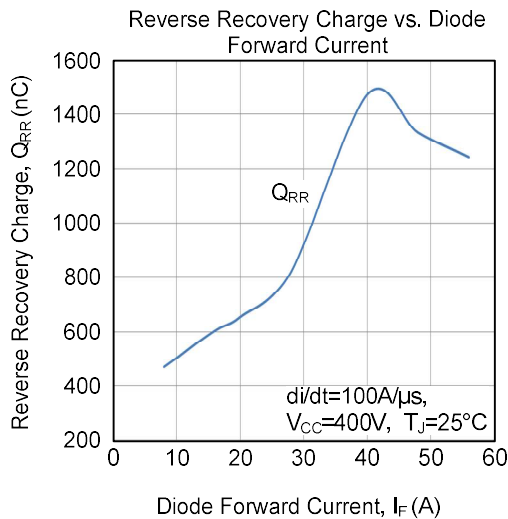
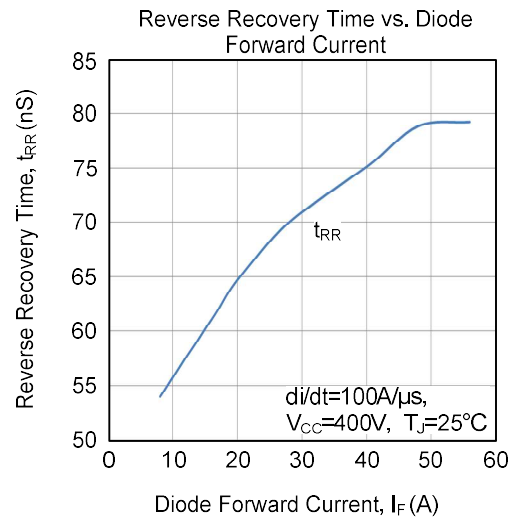
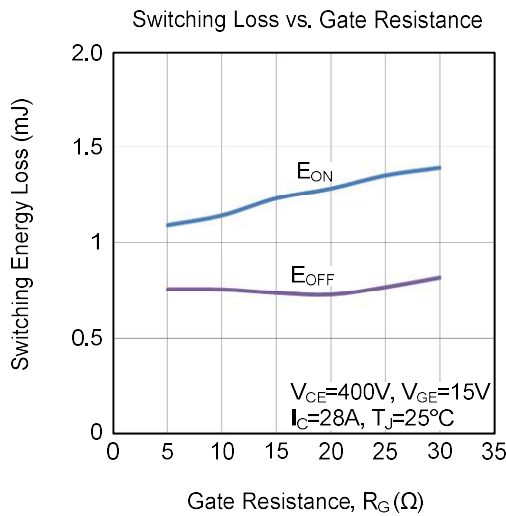
■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



■ TYPICAL CHARACTERISTICS (Cont.)



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